

MC13751

Dual-Band Upmixer and Driver Amplifier

The MC13751 is an integrated transmit upmixer and driver amplifier designed for use in cellular phones. It includes two mixers and two RF step attenuators. The device is fabricated using Motorola's Advanced RF BiCMOS process with the SiGe:C option and is housed in a leadless QFN-24 package.

- Total Gain:
22 dB for Low Band
19.5 dB for High Band
- Total Current Consumption = 53 mA (Typ)
- Available in Tape and Reel, 2500 Units per 12 mm, 7 inch Reel

DUAL-BAND UPMIXER AND DRIVER AMPLIFIER

SEMICONDUCTOR TECHNICAL DATA



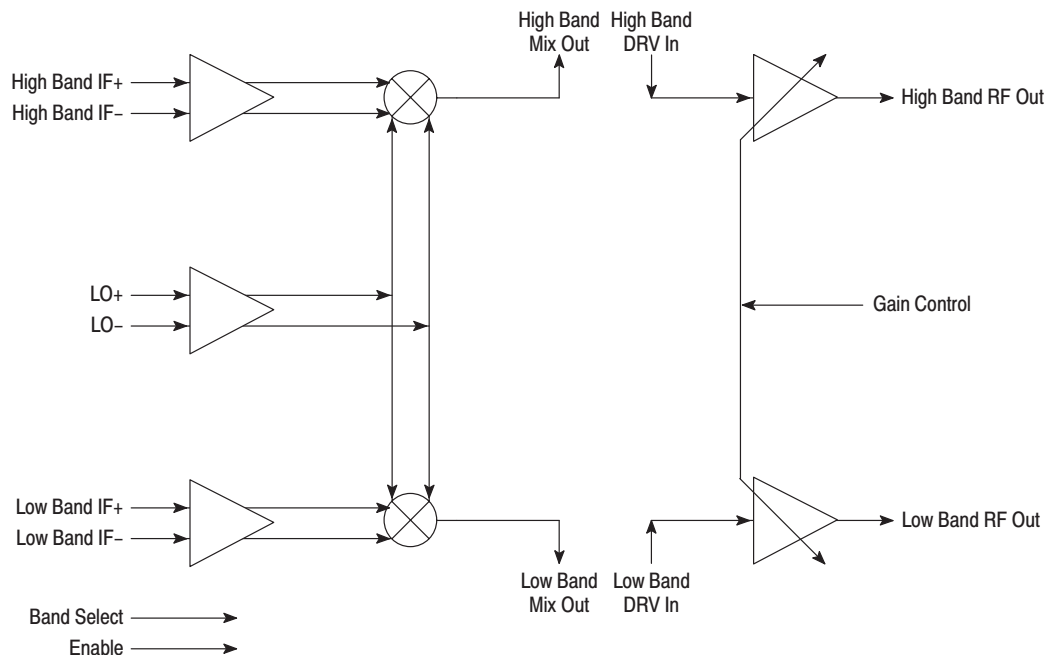
(Scale 2:1)

PLASTIC PACKAGE
CASE 1307
(QFN-24, Tape and Reel Only)

ORDERING INFORMATION

Device	Device Marking	Package
MC13751FCR2	MC751	QFN-24

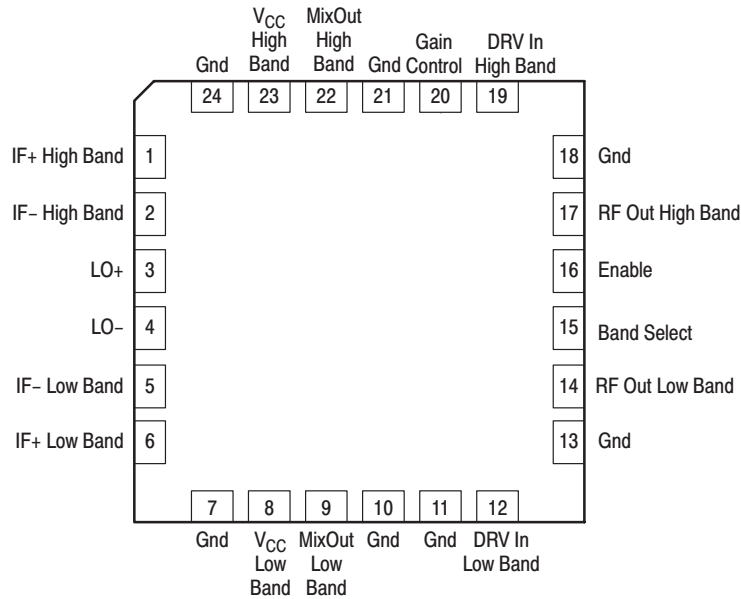
Simplified Block Diagram



This device contains 223 active transistors.

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CONTACT CONNECTIONS



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V _{CC}	3.6	V
LO Input Power		0	dBm
IF Input Level		0	dBm
Operating Temperature Range	T _A	-30 to 85	°C

- NOTES:** 1. Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the Electrical Characteristics tables.
 2. ESD (electrostatic discharge) immunity meets Human Body Model (HBM) ≤250 V and Machine Model (MM) ≤25 V. Additional ESD data available upon request.

DC ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Unit
Supply Voltage		2.7	2.78	2.86	V
Power Supply Current		–	53	64	mA
Enable					V
Inactive State		–	–	0.6	
Active State		1.6	–	–	
Band					V
800 MHz Enabled		–	–	0.6	
1900 MHz Enabled		1.6	–	–	
Power Down State Leakage Current (0.2 V Logic Levels)		–	–	25	μA
Gain Select Voltage					V
Gain High = 1		1.6	–	–	
Gain Low = 0		–	–	0.6	
Gain Select (enable and band signals current)		–	–	10	μA

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ELECTRICAL CHARACTERISTICS

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
IF Frequency Low Band High Band			150 150	178 213	250 250	MHz
LO Frequency Range Low Band High Band			1002 2028	– –	1029 2125	MHz
RF Frequency Range Low Band High Band			824 1850	– –	849 1910	MHz
IF Input Level, Both Bands (differential, typ –7.0 dBm)			–60	–	0	dBm
LO Input Level, Both Bands (differential)			–12	–10	–8.0	dBm
RF GMSK Output Level Both Bands Both Bands, Low Gain			10 6.0	– –	– –	dBm
RF Linear Output Level, TDMA Both Bands Both Bands, Low Gain			6.0 2.0	– –	– –	dBm
ACP @ f ±30 kHz, TDMA @ f ±60 kHz, TDMA @ f ±200 kHz, GSM @ f ±400 kHz, GSM			–32 –51 –36 –66	– – – –	– – – –	dBc
Conversion Gain Mixer Low Band High Band			6.3 6.5	8.3 8.5	10.3 10.5	dBc
Gain, Driver, High Gain Low Band High Band			11.7 9.0	13.7 11	15.7 13	dBc
Gain, Drivers, Low Gain Low Band High Band			7.7 5.0	9.7 7.0	11.7 9.0	dBc
Noise Figure Mixer (SSB) Drivers			– –	11 5.0	14 8.0	dB
IF Impedance (differential)			–	200	–	Ω
LO Impedance (differential)			–	100	–	Ω
RF Impedance (Both Bands @ Mixer (rf out, driver rf in and driver rf out))			–	50	–	Ω

SPURIOUS (measured with interstage filter)

Characteristic	Symbol	Min	Typ	Max	Unit
LO Leakage to RF Port (Both bands, P _{out} = 6.0 dBm)		–	–	–20	dBc
IF Leakage to RF Port (Both bands)		–	–	–50	dBc
Image Supression (Both bands)		–	–	–20	dBc
2x Image Supression (Both bands)		–	–	–40	dBc
LO – 2x IF (Both bands)		–	–	–30	dBc
2x LO – 7x IF (Low band)		–	–	–40	dBc
5 * IF (Low band)		–	–	–80	dBc
11 * IF (Low band)		–	–	–80	dBc